## NSN 5961-01-333-2230

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-2230 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.900 inches **Overall Diameter:** 0.180 inches **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, instantaneous and 400.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 70.00 amperes peak forward surge current nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No